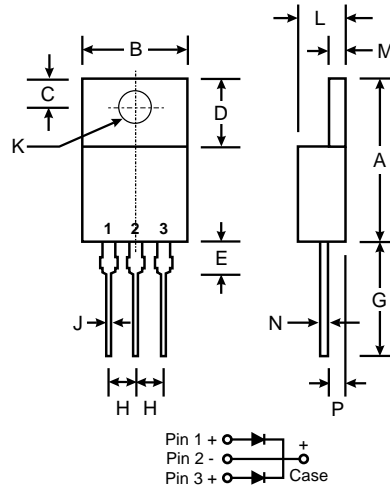


#### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

#### Mechanical Data

- Case: TO-220AB, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



TO-220AB		
Dim	Min	Max
A	14.22	15.88
B	9.57	10.57
C	2.54	3.43
D	5.80	6.80
E	—	6.35
G	12.70	14.73
H	2.29	2.79
J	0.51	1.14
K	3.53 $\varnothing$	4.14 $\varnothing$
L	3.56	4.83
M	1.07	1.47
N	0.30	0.64
P	2.03	2.92
All Dimensions in mm		

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#### Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 2040 CT	MBR 2045 CT	MBR 2050 CT	MBR 2060 CT	MBR 20100 CT	MBR 20150 CT	MBR 20200 CT	Units	
Peak Repetitive Reverse Voltage	$V_{RRM}$	40	45	50	60	100	150	200	V	
Working Peak Reverse Voltage	$V_{RWM}$									
DC Blocking Voltage	$V_R$									
RMS Reverse Voltage	$V_{R(RMS)}$	28	31	35	42	70	105	140	V	
Average Rectified Output Current @ $T_L = 75^\circ\text{C}$ (Note 1)	$I_O$	20.0							A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	150							A	
Forward Voltage @ $I_F = 10\text{A}$	$V_{FM}$	0.70		0.80		0.85		0.92	V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_{RM}$	0.1 20							mA	
Typical Junction Capacitance (Note 2)	$C_j$	350		280		200			pF	
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	3.0							2.0	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{STG}$	-55 to +150							-55 to +175	$^\circ\text{C}$

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

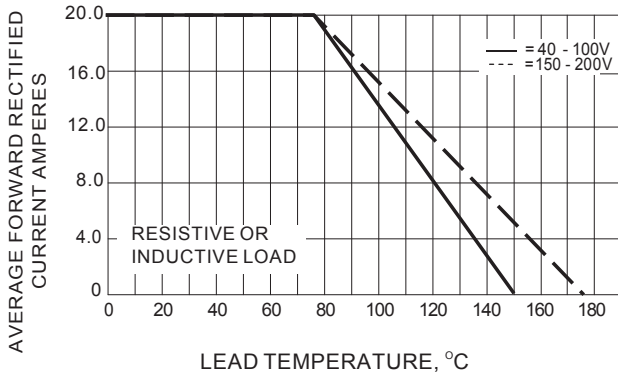


Fig.1- FORWARD CURRENT DERATING CURVE

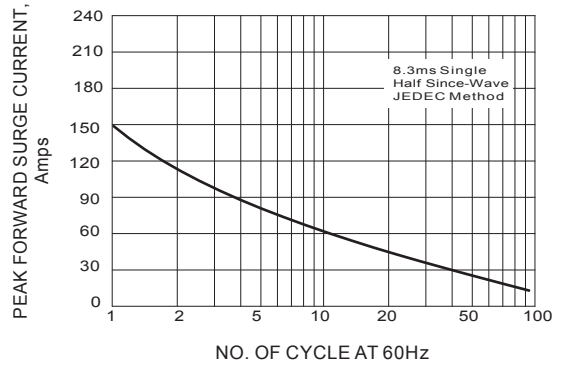


Fig.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

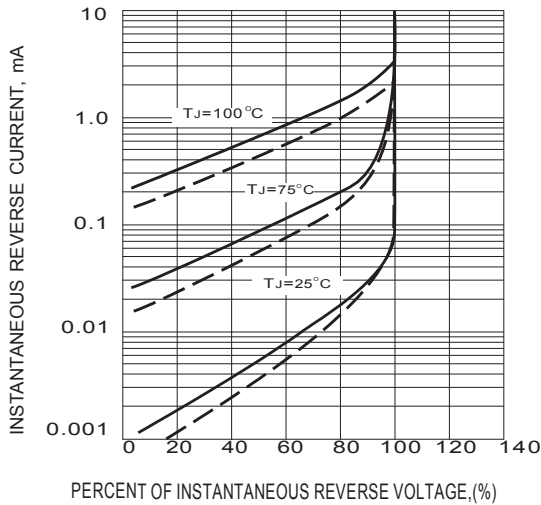


Fig.3- TYPICAL REVERSE CHARACTERISTICS

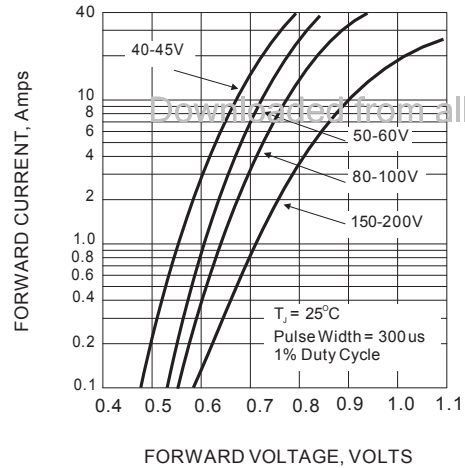


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS